

**SEMIDRIVER™**

## Hybrid Dual IGBT Driver

Order Number  
L5071602

### SKHI 22B R

#### Features\*

- Two output channels
- Integrated power supply on the secondary sides
- CMOS compatible inputs
- Short circuit protection by  $V_{CE}$  monitoring and switch off
- Drive interlock top / bottom
- Insulation by transformers
- Under voltage protection
- Error latch / output
- RoHS compliant

#### Typical Applications

- Driver for IGBT modules in bridge circuits in industrial applications
- DC bus voltage up to 1200 V

#### Footnotes

<sup>1)</sup> See Technical Explanation chapter "Electrical Characteristics"

<sup>2)</sup> Typ. 5V at  $R_{CE} = 36 \text{ k}\Omega$ ,  $C_{CE} = 470 \text{ pF}$ ,  $R_{VCE} = 1 \text{ k}\Omega$

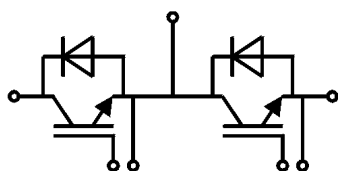
Absolute Maximum Ratings			
Symbol	Conditions	Values	Unit
$V_s$	Supply voltage primary	18	V
$V_{iH}$	Input signal voltage (HIGH)	$5 + 0.3$	V
$I_{outPEAK}$	Output peak current	20	A
$I_{outAVmax}$	Output average current	40	mA
$f_{max}$	Max. switching frequency	50	kHz
$V_{CE}$	Collector emitter voltage sense across the IGBT	1700	V
$dv/dt$	Rate of rise and fall of voltage secondary to primary side	50	kV/ $\mu$ s
$V_{isol IO}$	Insulation test voltage input - output (AC, rms, 2s)	4000	V
$V_{isol12}$	Insulation test voltage output 1 - output 2 (AC, rms, 2s)	1500	V
$R_{Gon min}$	Minimum rating for external $R_{Gon}$	3	$\Omega$
$R_{Goff min}$	Minimum rating for external $R_{Goff}$	3	$\Omega$
$Q_{out/pulse}$	Max. rating for output charge per pulse <sup>1)</sup>	4	$\mu$ C
$T_{op}$	Operating temperature	-40 ... 85	$^{\circ}$ C
$T_{stg}$	Storage temperature	-40 ... 85	$^{\circ}$ C

Characteristics					
Symbol	Conditions	min.	typ.	max.	Unit
$V_s$	Supply voltage primary side	14.4	15	15.6	V
$I_{S0}$	Supply current primary (no load)		80		mA
	Supply current primary side (max.)			290	mA
$V_i$	Input signal voltage on / off		5 / 0		V
$V_{IT+}$	Input threshold voltage (HIGH)			3.9	V
$V_{IT-}$	Input threshold voltage (LOW)	1.5			V
$R_{IN}$	Input resistance		3.3		k $\Omega$
$V_{G(on)}$	Turn on output voltage		15		V
$V_{G(off)}$	Turn off output voltage		-7		V
$R_{GE}$	Internal gate-emitter resistance		22		k $\Omega$
$f_{ASIC}$	Asic system switching frequency		8		MHz
$t_{d(on)IO}$	Input-output turn-on propagation time	0.85	1	1.15	$\mu$ s
$t_{d(off)IO}$	Input-output turn-off propagation time	0.85	1	1.15	$\mu$ s
$t_{d(eri)}$	Error input-output propagation time		0.6		$\mu$ s
$t_{pERRESET}$	Error reset time		9		$\mu$ s
$t_{TD}$	Top-Bot interlock dead time	0		4.3	$\mu$ s
$V_{CE sat}$	Reference voltage for $V_{CE}$ -monitoring <sup>2)</sup>		5	10	V
$C_{ps}$	Coupling capacitance prim sec		12		pF
$w$	weight		45		g
MTBF	Mean Time Between Failure $T_a = 40^{\circ}$ C		2		$10^6$ h

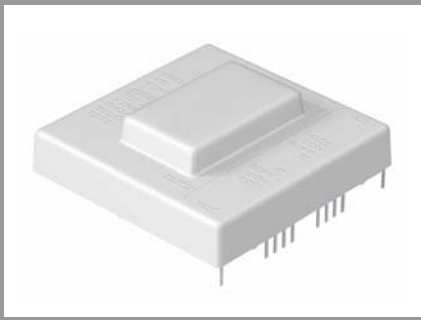
This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

#### \*IMPORTANT INFORMATION AND WARNINGS

The specifications of SEMIKRON products may not be considered as guarantee or assurance of product characteristics ("Beschaffenhheitsgarantie"). The specifications of SEMIKRON products describe only the usual characteristics of products to be expected in typical applications, which may still vary depending on the specific application. Therefore, products must be tested for the respective application in advance. Application adjustments may be necessary. The user of SEMIKRON products is responsible for the safety of their applications embedding SEMIKRON products and must take adequate safety measures to prevent the applications from causing a physical injury, fire or other problem if any of SEMIKRON products become faulty. The user is responsible to make sure that the application design is compliant



Driver Core



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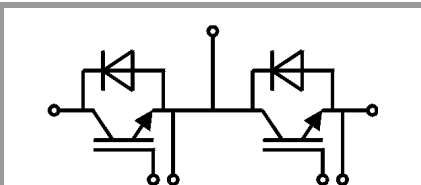
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